Features

- Wide 4V to 18V Operating Input Range
- 2A Continuous Output Current
- 1MHz Switching Frequency
- Short Protection with Hiccup-Mode
- Built-in Over Current Limit
- Built-in Over Voltage Protection
- Internal Power-Save Mode (PFM/PWM)
- Internal Soft-Start
- 110mΩ/70mΩ Low RDS(ON) Internal Power MOSFETs
- Output Adjustable from 0.6V
- No Schottky Diode Required
- Integrated internal compensation
- Thermal Shutdown
- Available in SOT23-6 Package
- -40 ℃ to +85 ℃ Temperature Range

General Description

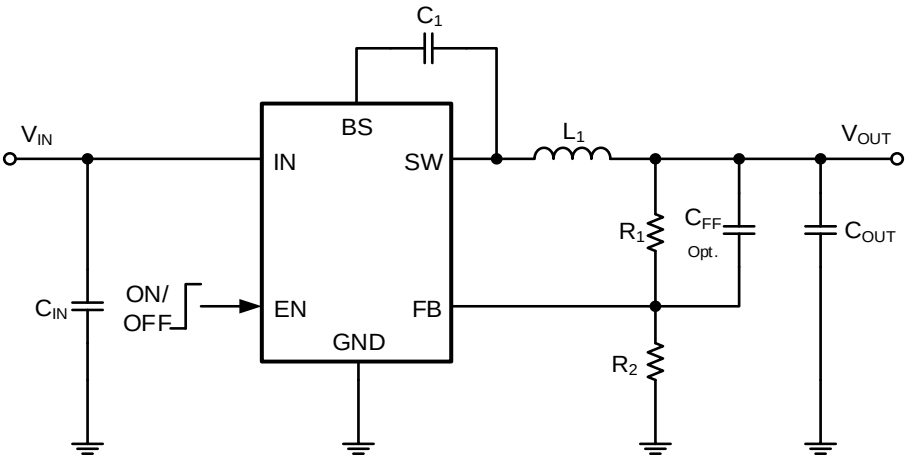
The ASP8121 is a high frequency, synchronous, rectified, step-down, switch-mode converter with internal power MOSFETs. It offers a very compact solution to achieve a 3A peak output current over a wide input supply range, with excellent load and line regulation.

The ASP8121 requires a minimal number of readily available, external components and is available in a space saving SOT23-6 package.

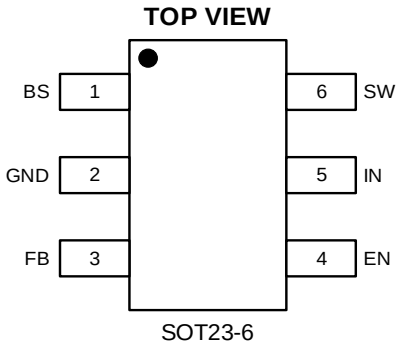
Applications

- Digital Set-top Box (STB)
- Tablet Personal Computer (Pad)
- Flat-Panel Television and Monitor
- Wi-Fi Router / AP
- Digital Video Recorder (DVR)
- Portable Media Player (PMP)
- Cable Modem / XDSL
- General Purposes

Typical Application Circuit



Pin Configuration



Pin Description

Pin	Name	Function
1	BS	Bootstrap. A capacitor connected between SW and BST pins is required to form a floating supply across the high-side switch driver.
2	GND	GROUND Pin
3	FB	Adjustable Version Feedback input. Connect FB to the center point of the external resistor divider
4	EN	Drive this pin to a logic-high to enable the IC. Drive to a logic-low to disable the IC and enter micro-power shutdown mode.
5	IN	Power Supply Pin
6	SW	Switching Pin

Absolute Maximum Ratings (1) (2)

Item	Min	Max	Unit
V_{IN} voltage	-0.3	20	V
EN voltage	-0.3	20	V
SW voltage	-0.3	V_{IN}+0.5V	V
BS voltage	-0.3	Vsw+5V	V
FB voltage	–0.3	6	V
Power dissipation (3)	Internally Limited		
Operating junction temperature, T_J	-40	150	°C
Storage temperature, T_{stg}	–55	150	°C
Lead Temperature (Soldering, 10sec.)		260	°C

Note (1): Exceeding these ratings may damage the device.

Note (2): The device is not guaranteed to function outside of its operating conditions.

Note (3): The maximum allowable power dissipation is a function of the maximum junction temperature, $T_{J(MAX)}$, the junction-to-ambient thermal resistance, $R_{\theta JA}$, and the ambient temperature, T_A. The maximum allowable power dissipation at any ambient temperature is calculated using: $P_{D\,(MAX)} = (T_{J(MAX)} - T_A)/R_{\theta JA}$. Exceeding the maximum allowable power dissipation causes excessive die temperature, and the regulator goes into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage. Thermal shutdown engages at T_J=160°C (typical) and disengages at T_J= 130°C (typical).

Electrical Characteristics (3) (4)

V_{IN}=12V, T_A=25°C, unless otherwise specified.

Parameter	Test Conditions	Min	Typ.	Max	Unit
Input Voltage Range		4.5		18	V
Supply Current (Quiescent)	V_{EN} =3.0V		0.6	0.8	mA
Supply Current (Shutdown)	V_{EN} =0 or EN = GND			4	uA
Feedback Voltage		0.585	0.600	0.615	V
High-Side Switch On-Resistance	I_{SW}=100mA		110		mΩ
Low-Side Switch On-Resistance	I_{SW}=-100mA		70		mΩ
Upper Switch Current Limit		3			A
Over Voltage Protection Threshold			18.6		V
Switching Frequency			1		MHz
Maximum Duty Cycle	VFB=90%		94		%
Minimum On-Time			54		nS
EN Rising Threshold		1.4			V
EN Falling Threshold				0.8	V
Under-Voltage Lockout Threshold	Wake up V_{IN} Voltage		3.5	3.8	V
	Shutdown V_{IN} Voltage	2.9	3.2		V
	Hysteresis V_{IN} voltage		300		mV
Soft Start			1.5		mS
Thermal Shutdown			160		℃
Thermal Hysteresis			30		℃

Note (1): MOSFET on-resistance specifications are guaranteed by correlation to wafer level measurements.

Note (2): Thermal shutdown specifications are guaranteed by correlation to the design and characteristics analysis.

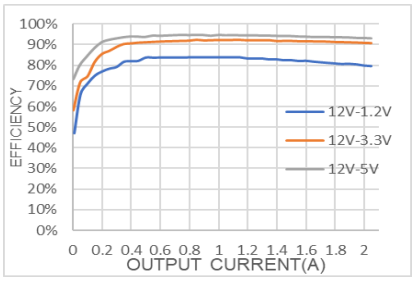
Typical Performance Characteristics (1) (2)

Note (1): Performance waveforms are tested on the evaluation board.

Note (2): V_{IN} =12V, V_{OUT}=3.3V, T_A = +25ºC, unless otherwise noted.

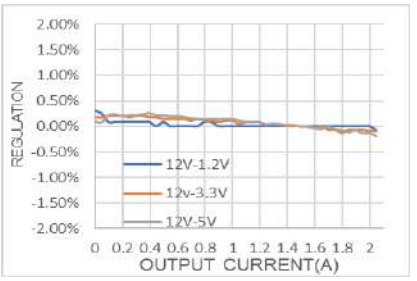
Efficiency vs Load Current

V_{OUT}=5V, 3.3V, 1.2V



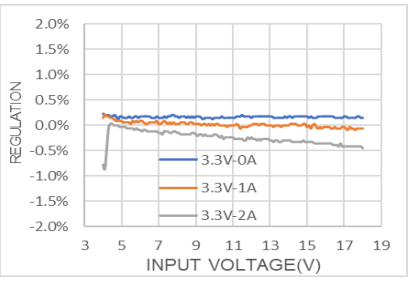
Load Regulation

V_{OUT}=5V, 3.3V, 1.2V



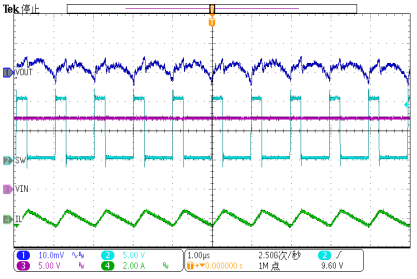
Line Regulation

V_{OUT}=3.3V



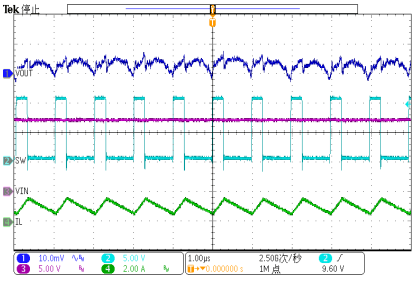
Output Ripple Voltage

V_{IN}=12V, V_{OUT}=3.3V, I_{OUT}=0A



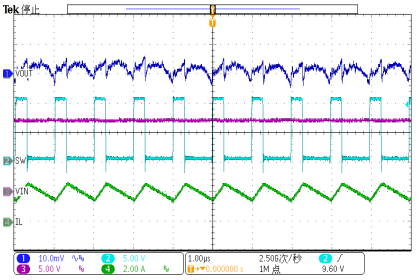
Output Ripple Voltage

V_{IN}=12V, V_{OUT}=3.3V, I_{OUT}=1A



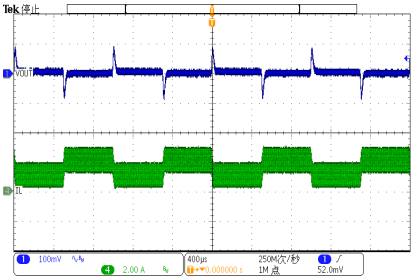
Output Ripple Voltage

V_{IN}=12V, V_{OUT}=3.3V, I_{OUT}=2A



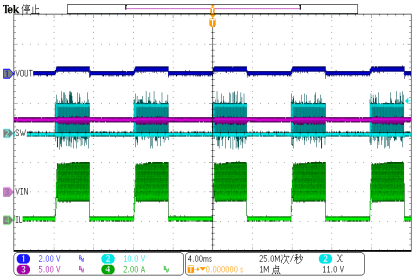
Loop Response

V_{IN}=12V, V_{OUT}=3.3V, I_{OUT}=1A-2A



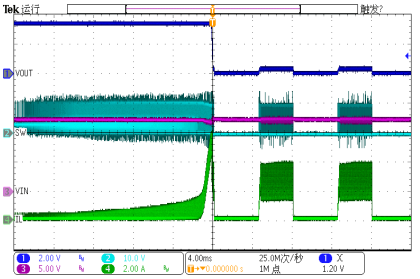
Output Short

V_{IN}=12V, V_{OUT}=3.3V



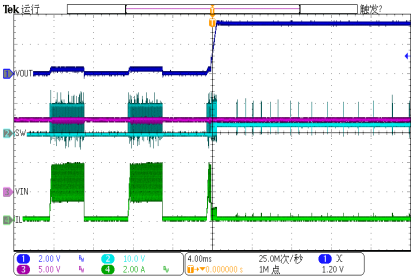
Short Circuit Entry

V_{IN}=12V, V_{OUT}=3.3V



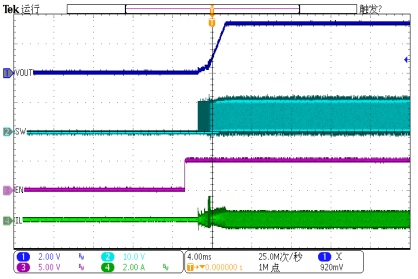
Short Circuit Recovery

V_{IN}=12V, V_{OUT}=3.3V



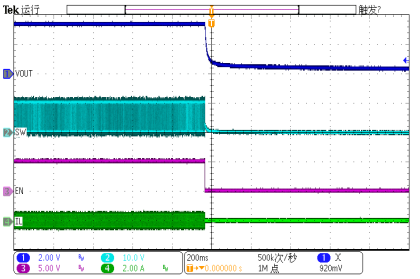
Enable Startup at No Load

V_{IN}=12V, V_{OUT}=3.3V, I_{OUT}=0A



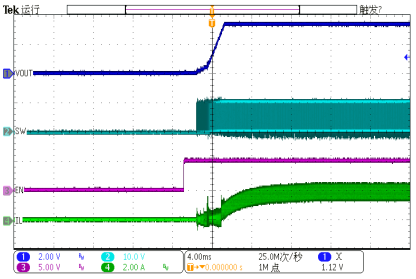
Enable Shutdown at No Load

V_{IN}=12V, V_{OUT}=3.3V, I_{OUT}=0A



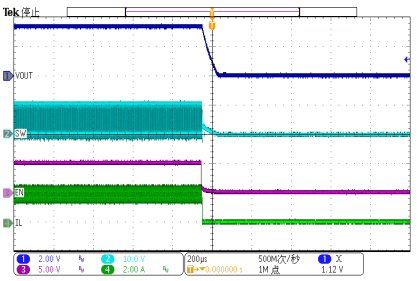
Enable Startup at Full Load

V_{IN}=12V, V_{OUT}=3.3V, I_{OUT}=2A



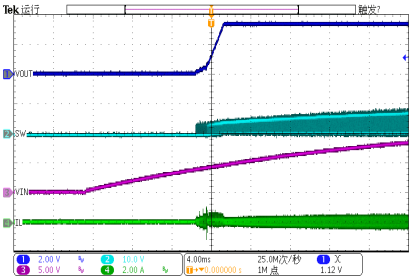
Enable Shutdown at Full Load

V_{IN}=12V, V_{OUT}=3.3V, I_{OUT}=2A



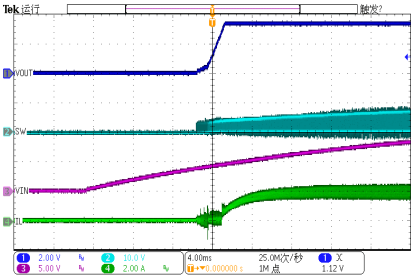
Power Up at No Load

V_{IN}=12V, V_{OUT}=3.3V, I_{OUT}=0A



Power Up at Full Load

V_{IN}=12V, V_{OUT}=3.3V, I_{OUT}=2A



Functional Block Diagram

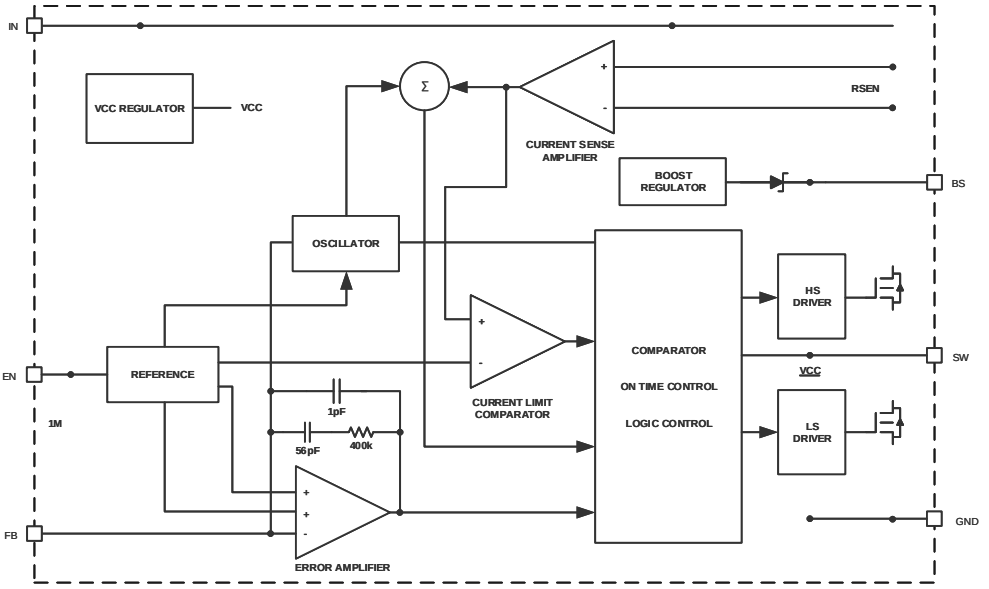


Figure 2. ASP8121 Block Diagram

Functions Description

Internal Regulator

The ASP8121 is a current mode step down DC/DC converter that provides excellent transient response with no extra external compensation components. This device contains an internal, low resistance, high voltage power MOSFET, and operates at a high 1MHz operating frequency to ensure a compact, high efficiency design with excellent AC and DC performance.

Error Amplifier

The error amplifier compares the FB pin voltage with the internal FB reference (VFB) and outputs a current proportional to the difference between the two. This output current is then used to charge or discharge the internal compensation network, which is used to control the power MOSFET current. The optimized internal compensation network minimizes the external component counts and simplifies the control loop design.

Internal Soft-Start

The soft-start is implemented to prevent the converter output voltage from overshooting during startup. When the chip starts, the internal circuitry generates a soft-start voltage (SS) ramping up from 0V to 0.6V. When it is lower than the internal reference (REF), SS overrides REF so the error amplifier uses SS as the reference. When SS is higher than REF, REF regains control. The SS time is internally max to 1.2ms.

Over Current Protection & Hiccup

The ASP8121 has cycle-by-cycle over current limit when the inductor current peak value exceeds the set current limit threshold. Meanwhile, output voltage starts to drop until FB is below the Under-Voltage (UV) threshold, typically 25% below the reference. Once a UV is triggered, the ASP8121 enters hiccup mode to periodically restart the part. This protection mode is especially useful when the output is dead-short to ground. The average short circuit

current is greatly reduced to alleviate the thermal issue and to protect the regulator. The ASP8121 exits the hiccup mode once the over current condition is removed.

Startup and Shutdown

If both VIN and EN are higher than their appropriate thresholds, the chip starts. The reference block starts first, generating stable reference voltage and currents, and then the internal regulator is enabled. The regulator provides stable supply for the remaining circuitries. Three events can shut down the chip: EN low, VIN low and thermal shutdown. In the shutdown procedure, the signaling path is first blocked to avoid any fault triggering. The comp voltage and the internal supply rail are then pulled down. The floating driver is not subject to this shutdown command.

Applications Information

Setting the Output Voltage

ASP8121 require an input capacitor, an output capacitor and an inductor. These components are critical to the performance of the device. ASP8121 are internally compensated and do not require external components to achieve stable operation. The output voltage can be programmed by resistor divider.

$$V_{OUT} = V_{FB} \times \frac{R1 + R2}{R2}$$

V_{OUT}(V)	R1(KΩ)	R2(KΩ)	L1(μH)	C1(nF)	C_{IN}(μF)	C_{OUT}(μF)	C_{FF} (pF) Opt.
1.0	6.67	10	2.2	100	22	22×2	C_{FF} Chapter
1.05	7.5	10	2.2	100	22	22×2	C_{FF} Chapter
1.2	10	10	2.2	100	22	22×2	C_{FF} Chapter
1.5	15	10	2.2	100	22	22×2	C_{FF} Chapter
1.8	20	10	3.3	100	22	22×2	C_{FF} Chapter
2.5	31.67	10	3.3	100	22	22×2	C_{FF} Chapter
3.3	45	10	4.7	100	22	22×2	C_{FF} Chapter
5.0	73.3	10	4.7	100	22	22×2	C_{FF} Chapter

All the external components are the suggested values, the final values are based on the application testing results.

Selecting the Inductor

The recommended inductor values are shown in the Application Diagram. It is important to guarantee the inductor core does not saturate during any foreseeable operational situation. The inductor should be rated to handle the maximum inductor peak current: Care should be taken when reviewing the different saturation current ratings that are specified by different manufacturers. Saturation current ratings are typically specified at 25°C, so ratings at maximum ambient temperature of the application should be requested from the manufacturer. The inductor value can be calculated with:

$$L = \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{V_{IN} \times \Delta I_L \times F_{OSC}}$$

Where ΔIL is the inductor ripple current. Choose inductor ripple current to be approximately 30% if the maximum load current. The maximum inductor peak current is:

$$I_{L(MAX)} = I_{LOAD} + \frac{\Delta I_L}{2}$$

Under light load conditions below 100mA, larger inductance is recommended for improved efficiency.

Selecting the Output Capacitor

Special attention should be paid when selecting these components. The DC bias of these capacitors can result in a capacitance value that falls below the minimum value given in the recommended capacitor specifications table.
The ceramic capacitor's actual capacitance can vary with temperature. The capacitor type X7R, which operates over a temperature range of −55°C to +125°C, will only vary the capacitance to within ±15%. The capacitor type X5R has a similar tolerance over a reduced temperature range of −55°C to +85°C. Many large value ceramic capacitors, larger than 1uF are manufactured with Z5U or Y5V temperature characteristics. Their capacitance can drop by more than 50% as the temperature varies from 25 ℃ to 85 ℃. Therefore X5R or X7R is recommended over Z5U and Y5V in applications where the ambient temperature will change significantly above or below 25 ℃.
Tantalum capacitors are less desirable than ceramic for use as output capacitors because they are more expensive when comparing equivalent capacitance and voltage ratings in the 0.47uF to 44uF range. Another important consideration is that tantalum capacitors have higher ESR values than equivalent size ceramics. This means that while it may be possible to find a tantalum capacitor with an ESR value within the stable range, it would have to be larger in capacitance (which means bigger and more costly) than a ceramic capacitor with the same ESR value. It should also be noted that the ESR of a typical tantalum will increase about 2:1 as the temperature goes from 25 ℃ down to −40°C, so some guard band must be allowed.

PC Board Layout Consideration

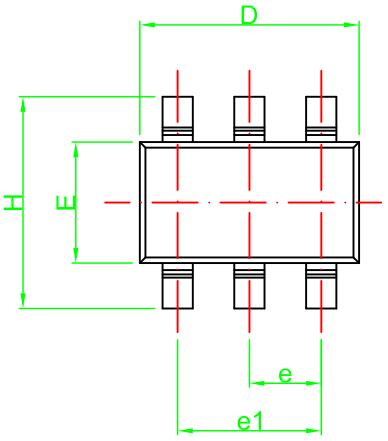
PCB layout is very important to achieve stable operation. It is highly recommended to duplicate EVB layout for optimum performance. If change is necessary, please follow these guidelines for reference.

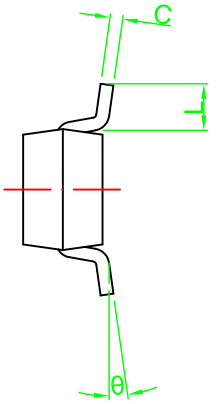
1. Keep the path of switching current short and minimize the loop area formed by Input capacitor, high-side MOSFET and low-side MOSFET.
2. Bypass ceramic capacitors are suggested to be put close to the Vin Pin.
3. Ensure all feedback connections are short and direct. Place the feedback resistors and compensation components as close to the chip as possible.
4. VOUT, SW away from sensitive analog areas such as FB.
5. Connect IN, SW, and especially GND respectively to a large copper area to cool the chip to improve thermal performance and long-term reliability.

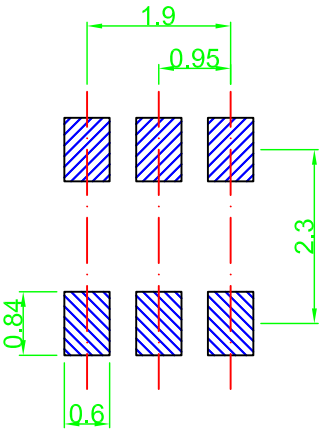
Ordering and Marking Information

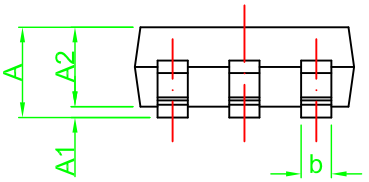
Ordering Device No.	Marking	Package	Packing	Quantity
ASP8121ZC-R	BDYLL	SOT23-6	Reel	3000/Reel

PACKAGE	MARKING
SOT23-6	Top Marking: BDYLL (device code: BD, Y=year code, LL= lot number code)



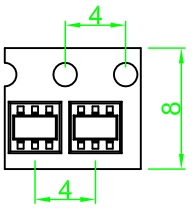






Recommended Land Pattern

Symbol	Dimensions in Millimeters		Dimensions in Inches	
	Min	Max	Min	Max
A	1.00	1.25	0.039	0.049
A1	0.00	0.10	0.000	0.004
A2	1.00	1.15	0.039	0.045
b	0.30	0.55	0.012	0.022
C	0.08	0.20	0.003	0.008
D	2.70	3.10	0.106	0.122
E	1.40	1.80	0.055	0.071
e	0.95 TYP		0.037 TYP	
e1	1.90 TYP		0.075 TYP	
H	2.80	3.00	0.110	0.118
L	0.30	0.60	0.012	0.024
θ	0°	8°	0°	8°



Q'ty / Reel	Reel Size
3000pcs	7"

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